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Docket Number (Optional)	Application Nur
774-010087-US R)	
Applicant(s)	

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U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
MS		4.594,128	6/10/86	Cook	156	622	
M3		4,315,477	2/16/82	Wang et al.	118	64	
MS		5,375,557	12/27/94	Anderson	117	203	
		\					
							٨
				FOREIGN PATENT DOCUMENTS			

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SS SUBCLASS	Translation	
REF	KEI	DOCUMENT NUMBER	DAIE	COUNTRY			YES	NO
					:			

OTHER DOCUMENTS

(Including Author, Title, Date, Pertinent Pages, Etc.)

MS MS Ms	1. Abstract of oral presentation at Taiwan Symposium (26th -28th July 2000)
1MS	2. Technical Symposium Program entitled Photonics Taiwan July 26-28 2000
Ms	3. "New Concept Technology Pressure-Variation Liquid Phase Epitaxy", Xian-jun Maao et al., July 2000
MS	4. Study of Liquid Phase Epixtaxial Growth of Antimonide Compounds, Mao Xiang-jun, 2000
MS	5. Publication "Solid-Liquid Equilibria For Quaternary Solid, A.S. Jordan et al. May 17, 1974
• • • •	ll

6. IEEE Journal of Quantum Electronics, vol. QE-23 No. 6, June 19897 "InGaSbAs Injection Lasers" MS

EXAMINER

DATE CONSIDERED

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